

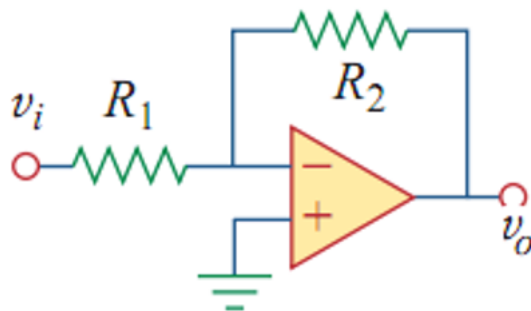
# 模电知识点汇总

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At the beginning, the theories of all kinds of elements are unnecessary, you just need to know how to solve out the problems, that's the point.

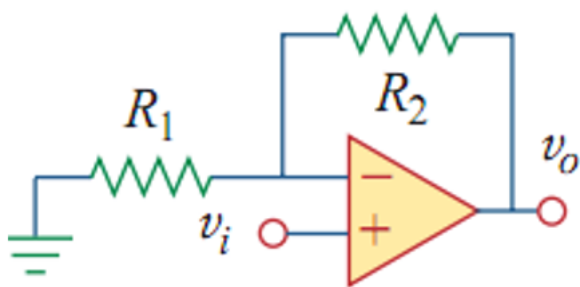
## 1 Op-Amp

5 basic Op-Amp models:



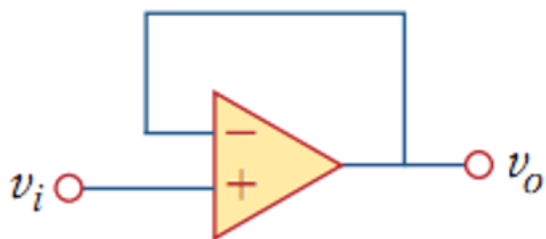
$$v_o = -\frac{R_2}{R_1}v_i$$

Figure 1: Inverting Amplifier



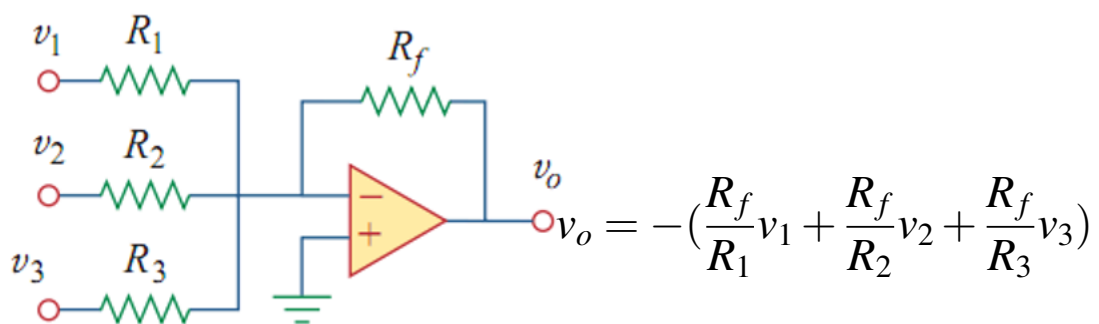
$$v_o = \left(1 + \frac{R_2}{R_1}\right)v_i$$

Figure 2: Inverting Amplifier



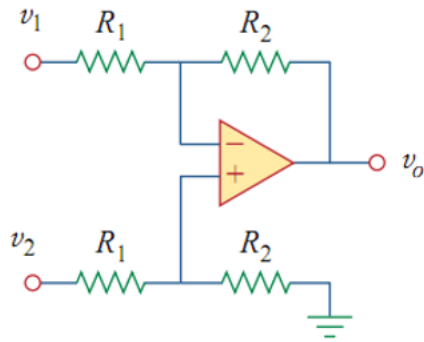
$$v_o = v_i$$

Figure 3: Inverting Amplifier



$$v_o = -\left(\frac{R_f}{R_1}v_1 + \frac{R_f}{R_2}v_2 + \frac{R_f}{R_3}v_3\right)$$

Figure 4: Inverting Amplifier



$$v_o = \frac{R_2}{R_1}(v_2 - v_1)$$

Figure 5: Inverting Amplifier

## 2 Basic Diode

The theory of diodes is PN junction, OK, that's not matter. The most import is the 4 models of Diode: ideal model, case 1 model, case 2 model, small signal model.

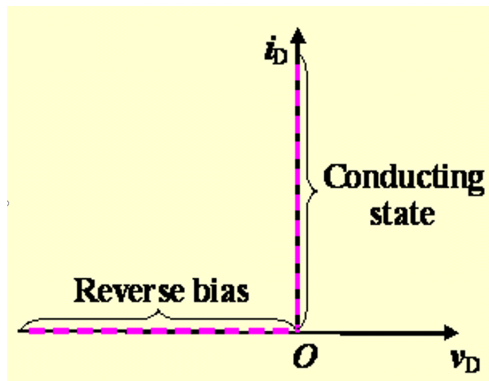
We first introduce the  $i_D - v_D$  relationship:

$$i_D = I_S(e^{\frac{v_D}{nV_T}} - 1)$$

In this equation:  $n$ -ideality factor(for ideal diode,  $n = 1$ ),  $I_S$ -reverse-bias saturation current,  $V_T$ -thermal voltage at room temperature(In general,  $V_T = 0.026\text{V}$ ). And at the turning point, we define:  $V_\gamma$ -turn-on or cut-in voltage.

Now we introduce the 4 diode model:

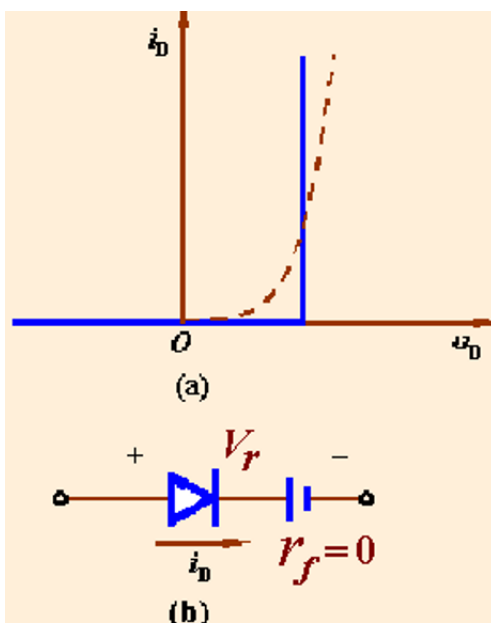
**Ideal model:** the conduction voltage drop equals 0( $V_\gamma = 0$ ), and When reverse bias, the resistor is  $\infty$



$$V_\gamma = 0, r_d = \infty$$

Figure 6: Inverting Amplifier

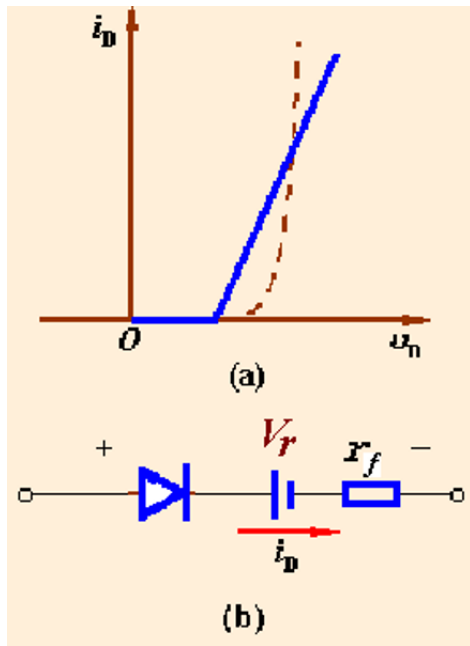
**Case 1 model:** consider conduction voltage drop ( $V_\gamma = 0.6\text{--}0.7\text{V}$ ), when reverse bias, it's the same as the ideal model



$$V_\gamma = 0.6\text{--}0.7\text{V}, r_d = \infty$$

Figure 7: Inverting Amplifier

**Case 2 model:** consider conduction voltage drop Forward diode resistance, when reverse bias, it's the same as the ideal model.



$$V_\gamma = 0.6 \text{ } 0.7\text{V}, r_d \neq \infty$$

Figure 8: Inverting Amplifier

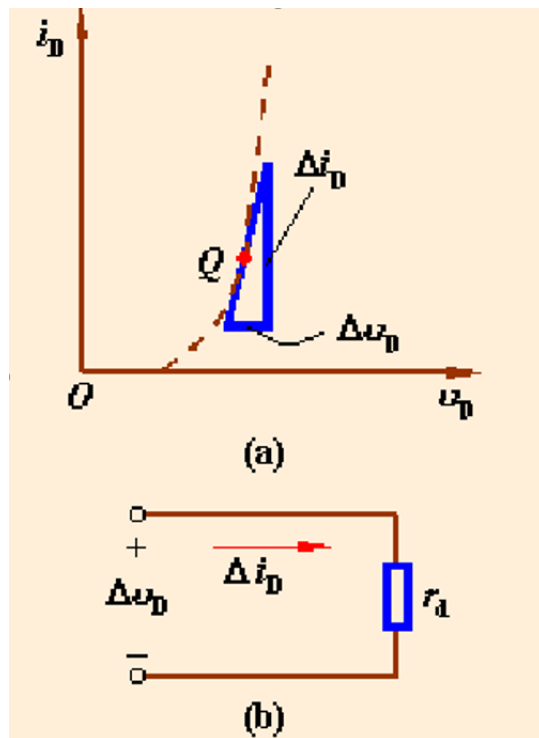
**Small signal model:** it's a model use for AC analysis. When a diode is operating in the small range, it can be a small-signal incremental resistance:

$$r_d = \frac{\Delta v_D}{\Delta i_D}$$

We have equation:  $i_D = I_S(e^{\frac{v_D}{V_T}} - 1)$ , therefore:

$$g_d = \left. \frac{di_D}{dv_D} \right|_Q = \left. \frac{I_S e^{\frac{v_D}{V_T}}}{V_T} \right|_Q = \left. \frac{I_{DQ}}{V_T} \right|_Q (e^{\frac{v_D}{V_T}} \approx e^{\frac{v_D}{V_T}} - 1)$$

$$\Rightarrow r_d = \left. \frac{V_T}{I_{DQ}} \right|_Q$$



$$V_\gamma = 0.6 - 0.7\text{V}, r_d = \left. \frac{V_T}{I_{DQ}} \right|_Q$$

Figure 9: Inverting Amplifier

### 3 Other Diodes

To analyze diode, The most important thing is to discuss all cases of diode, and you may need to consider conductivity of different diodes.

**Half-Wave Rectifier** Just Diode

**Full-Wave Rectifier:**

**1.Rectifier with center-tapped transformer**

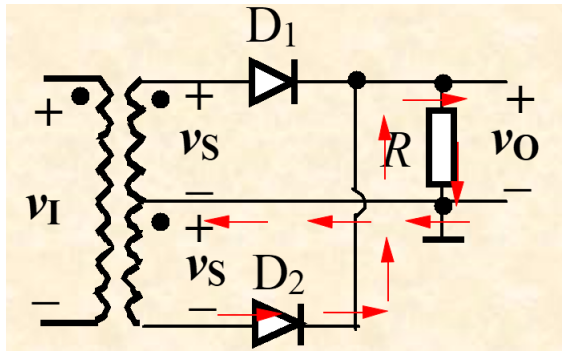


Figure 10: Inverting Amplifier

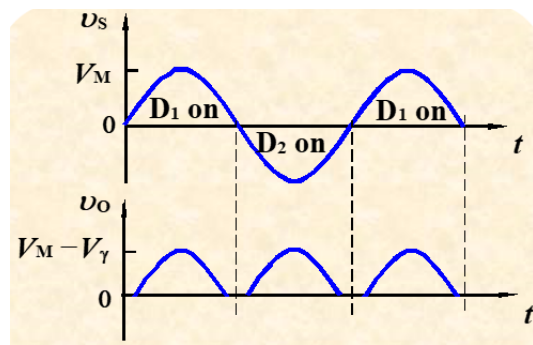


Figure 11: Inverting Amplifier

## 2. Bridge rectifier

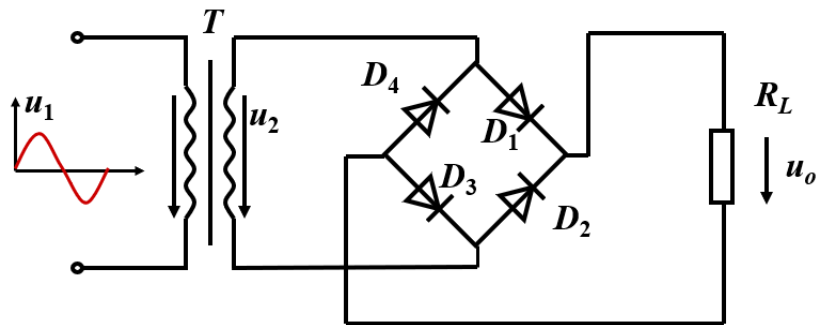


Figure 12: Inverting Amplifier

**Zener Diode:**

**4 MOSFET**

**5 BJT**

**6 Frequency Response**

**7 Power-Amplifier**